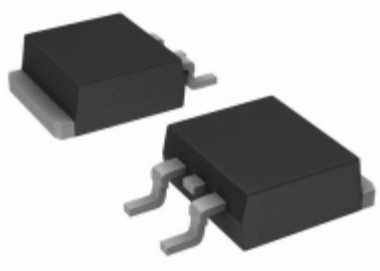







	<h2 style="color: red;">FQB2P25TM</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">FQB2P25TM</a>
	<b>Hersteller / Marke:</b>	<a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b>	MOSFET P-CH 250V 2.3A D2PAK
<b>Datenblätter:</b>	 <a href="#">FQB2P25TM.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 2587 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">FQB2P25TM</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET P-CH 250V 2.3A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	2587 pcs Stock
detaillierte Beschreibung	P-Channel 250V 2.3A (Tc) 3.13W (Ta), 52W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 52W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	250V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.3A (Tc)
Rds On (Max) @ Id, Vgs	4 Ohm @ 1.15A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8.5nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	250pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)




FQB2P25TM ist neu im Original, Suche FQB2P25TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB2P25TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB2P25TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB30N06LTM</b> Fairchild/ON Semiconductor MOSFET N-CH 60V 32A D2PAK</p>	 <p><b>FQB2P25TM</b> Fairchild/ON Semiconductor MOSFET P-CH 250V 2.3A D2PAK</p>	 <p><b>FQB30N06</b> FAIRCHI FQB30N06 FAIRCHI</p>	 <p><b>FQB2P40TM</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 400V 2A D2PAK</p>
 <p><b>FQB2P40TM</b> Fairchild/ON Semiconductor MOSFET P-CH 400V 2A D2PAK</p>	 <p><b>FQB2NA90TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 2.8A D2PAK</p>	 <p><b>FQB2N90TM</b> Fairchild/ON Semiconductor MOSFET N-CH 900V 2.2A D2PAK</p>	 <p><b>FQB30N06L</b> F FQB30N06L F</p>

### heiße Teile

Mehr

 FQB1N60TM	 FQB20N06L	 FQB20N60FTM	 FQB20N60TM	 FQB22P10
 FQB22P10TM	 FQB22P10TM	 FQB22P10TM_F085	 FQB24N08TM	 FQB24N08TM
 FQB25N33	 FQB25N33TM	 FQB25N33TM	 FQB25N33TM_F085	 FQB27N25TM
 FQB27P06	 FQB27P06TM	 FQB27P06TM	 FQB2N50C	 FQB2N60TM
 FQB2N60TM	 FQB2N80TM	 FQB2N80TM	 FQB2NA90TM	 FQB2NA90TM
 FQB2P25TM	 FQB30N06	 FQB30N06L	 FQB30N06LTM	 FQB30N06LTM
 FQB30N06TM	 FQB30N06TM	 FQB32N12V2	 FQB32N12V2TM	 FQB32N12V2TM
 FQB32N20	 FQB32N20C	 FQB32N20CTM	 FQB32N20CTM	 FQB32N30
 FQB33N10	 FQB33N10L	 FQB33N10LTM	 FQB33N10LTM	 FQB33N10TM
 FQB33N10TM	 FQB34N20	 FQB34N20L	 FQB34N20LTM	 FQB34N20LTM

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

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